

BSM150GB170DN2HOSA1

BSM150GB170DN2HOSA1 Information





Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BSM150GB170DN2HOSA1 Specifications

Manufacturer Part Number	BSM150GB170DN2HOSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Modules
Package	Module
Series	-
IGBT Type	-
Configuration	Half Bridge
Voltage - Collector Emitter Breakdown (Max)	1700V
Current - Collector (Ic) (Max)	220A
Power - Max	1250W
Vce(on) (Max) @ Vge, Ic	3.9V @ 15V, 150A
Current - Collector Cutoff (Max)	1.5mA
Input Capacitance (Cies) @ Vce	20nF @ 25V
Input	Standard
NTC Thermistor	No
Operating Temperature	150°C (TJ)
Mounting Type	Chassis Mount
Package / Case	Module
Supplier Device Package	Module
	Report errors?

BSM150GB170DN2HOSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

BSM150GB170DN2HOSA1 Payment Methods



If you have any question about BSM150GB170DN2HOSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com